

Search update 4/23/4 (5p.) ~~4/23/4~~

L Number	Hits	Search Text	DB	Time stamp
1	3536	((257/48) or (324/158.1) or (324/501) or (438/18)).CCLS.	USPAT; US-PGPUB	2004/04/23 19:43
2	687	(((257/48) or (324/158.1) or (324/501) or (438/18)).CCLS.) and (CMOS CMOSFET MOS MOSFET NMOS NMOSFET PMOSFET PMOS)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/04/23 19:46
-	0	(324/158).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/04/23 18:36
-	3960	324/158\$3.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/06/28 21:17
-	3960	324/158.\$3.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/06/28 21:17
-	0	lvp.ti,ab. and 257/\$6.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/06/28 21:20
-	2	lvp.ti,ab. and probe	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/06/28 21:20
-	24	lvp.ti,ab.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/06/28 21:21
-	4741	((257/48).CCLS.) or 324/158.\$3.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/06/29 12:55
-	7	(((257/48).CCLS.) or 324/158.\$3.ccls.) and (mosfet or cmosfet or nmosfet or pmosfet or cmos or nmos or pmos) and (test or testing or diagnostic) near12 laser	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/08/05 15:36
-	8	(((257/48).CCLS.) or 324/158.\$3.ccls.) and (mosfet or cmosfet or nmosfet or pmosfet or cmos or nmos or pmos) and (test or testing or diagnostic) near12 (optic or optical)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/06/29 13:01
-	2	(((257/48).CCLS.) or 324/158.\$3.ccls.) and (mosfet or cmosfet or nmosfet or pmosfet or cmos or nmos or pmos) and (test or testing or diagnostic) near12 (pn adj junction)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/06/29 13:08
-	26	(((257/48).CCLS.) or 324/158.\$3.ccls.) and (mosfet or cmosfet or nmosfet or pmosfet or cmos or nmos or pmos) and (test or testing or diagnostic) and (pn adj junction or p-n adj junction or pn-junction)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/06/29 13:15
-	3	laser near12 diagnostic near12 (np adj junction or n-p junction or np-junction)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/06/29 13:17

	33	((257/48).CCLS.) and prob\$3 near6 gate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/03 17:19
-	31	((257/48).CCLS.) and prob\$3 near6 gate) not (((257/48).CCLS.) and test\$3 near6 gate and (cmos or cmosfet))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/03 17:20
-	24	((257/48).CCLS.) and laser near6 (test\$3 or prob\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/03 17:21
-	38	((257/48).CCLS.) and (optical or laser) near6 (test\$3 or prob\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/03 17:26
-	1	((257/48).CCLS.) and (lvp or laser adj voltage adj probe)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/03 17:27
-	33	(lvp or laser adj voltage adj probe) and (mos or cmos or mosfet or cmosfet)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/03 17:28
-	3	(lvp or laser adj voltage adj probe) and (mos or cmos or mosfet or cmosfet) and (test\$3 or prob\$3) near6 gate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/03 17:29
-	44	(lvp or laser adj voltage adj probing).ti,ab,clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/03 20:39
-	0	(back-side or backside or back adj side) near3 (lvp or laser adj voltage adj (probing or probe))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/04 09:54
-	1	(back-side or backside or back adj side) near12 (lvp or laser adj voltage adj (probing or probe))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/04 10:05
-	1	"6428718".PN.	USPAT	2003/03/04 09:57
-	1	"6403439".PN.	USPAT	2003/03/04 10:03
-	10	(lvp or laser adj voltage adj (probing or probe)) and (cmos or cmosfet)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/04 10:59
-	1	"6331453".PN.	USPAT	2003/03/04 10:09
-	1	non-invasive near3 optical near12 (cmos or cmosfet)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/04 10:15
-	13	reverse adj voltage near6 (cmos or cmosfet)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/04 11:01

-	1	reverse adj voltage near6 (cmos or cmosfet) and (laser adj voltage adj (probing or probe))	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB	2003/03/04 11:02
-	11	reverse adj voltage near6 (cmos or cmosfet) and (test\$3 or prob\$3)	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB	2003/03/04 11:06
-	2	reverse adj voltage near6 (cmos or cmosfet) and (test\$3 or probe or probing)	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB	2003/03/04 12:00
-	2	("6084267").PN.	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB	2003/03/04 12:00
-	11	((257/48).CCLS.) or 324/158.\$3.ccls.) and (mosfet or cmosfet or nmosfet or pmosfet or cmos or nmos or pmos) and (test or testing or diagnostic) near12 laser	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB	2003/08/05 10:57
-	1	("6197109").PN.	USPAT	2003/08/05 15:37
-	3018	324/158\$3.ccls. 257/48.ccls. 438/18.ccls.	USPAT; US-PPGPUB	2003/08/05 19:09
-	77	(324/158\$3.ccls. 257/48.ccls. 438/18.ccls.) and (lvp laser adj voltage adj probe laser-voltage-probe laser adj voltage-probe (laser near12 (test\$3 diagnostic\$1)))	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB	2003/08/05 19:12
-	100	yoshida.in. and eiji.in.	USPAT; US-PPGPUB	2003/08/06 08:42
-	1	yoshida.in. and eiji.in. and transistor.clm. and laser.clm.	USPAT; US-PPGPUB	2003/08/06 08:43
-	6	yoshida.in. and eiji.in. and semiconductor and gate and laser	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB	2003/10/19 15:14
-	2	("6137295").PN.	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB	2003/10/19 15:15
-	6	392925.ap.	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB	2003/10/19 15:27
-	5806	((324/158.1) or (324/501) or (257/48)).CCLS.	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB	2003/10/19 15:27
-	10	((324/158.1) or (324/501) or (257/48)).CCLS.) and laser near20 junction	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB	2003/10/19 15:41
-	398	(438/18).CCLS.	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB	2003/10/19 15:41
-	2	((438/18).CCLS.) and laser near20 junction	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB	2003/10/19 15:41

-	6	lvp.ti,ab,clm. and probe	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT	2003/10/19 15:56
-	437	cmos.ti,ab,clm. and drain near3 (connect connected) near3 source and common near2 (source drain)	USPAT	2003/10/19 18:18
-	109	cmos.ti,ab,clm. and drain near3 (connect connected) near3 source and common near2 (source drain) and 257/\$9.cccls.	USPAT	2003/10/19 18:19
-	299	nmos near12 pmos and common adj (source drain) and 257/\$9.cccls.	USPAT; EPO; JPO	2003/10/19 19:45
-	0	dillinger.in. and protection and gate	USPAT; EPO; JPO; DERWENT	2003/10/19 19:48
-	74	latchup and testing and (257/\$9.cccls. 438/\$9.cccls.)	USPAT; EPO; JPO; DERWENT	2003/10/19 19:53
-	9	(latchup latch-up) near12 testing and (257/\$9.cccls. 438/\$9.cccls.)	USPAT; EPO; JPO; DERWENT	2003/10/19 20:10
-	1012	(257/48).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT	2003/10/19 20:11
-	1012	(257/48).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT	2003/10/19 20:11
-	542	(257/48).CCLS.	USPAT	2003/10/19 20:13
-	27	((257/48).CCLS.) and pmos and nmox	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT	2003/10/19 20:13
-	6357	324/158.1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT	2004/01/04 18:28
-	655	324/501	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT	2004/01/04 18:28
-	1900	257/48	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT	2004/01/04 18:28
-	8493	324/158.1 324/501 257/48	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT	2004/01/04 18:28
-	14	(324/158.1 324/501 257/48) and (laser adj voltage adj probe lvp laser adj diagnostic\$1 laser adj test\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT	2004/01/04 18:30
-	2	("5286656").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT	2004/04/23 19:42